TOSHIBA CMOS Digital Integrated Circuit   Silicon Monolithic

TC74HC240AP,TC74HC240AF,TC74HC241AP
TC74HC241AF,TC74HC244AP,TC74HC244AF

Octal Bus Buffer

TC74HC240AP/AF	Inverted, 3-State Outputs
TC74HC241AP/AF	Non-Inverted, 3-State Outputs
TC74HC244AP/AF	Non-Inverted, 3-State Outputs

   The TC74HC240A, 241A and 244A are high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate C2MOS technology.

   They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.
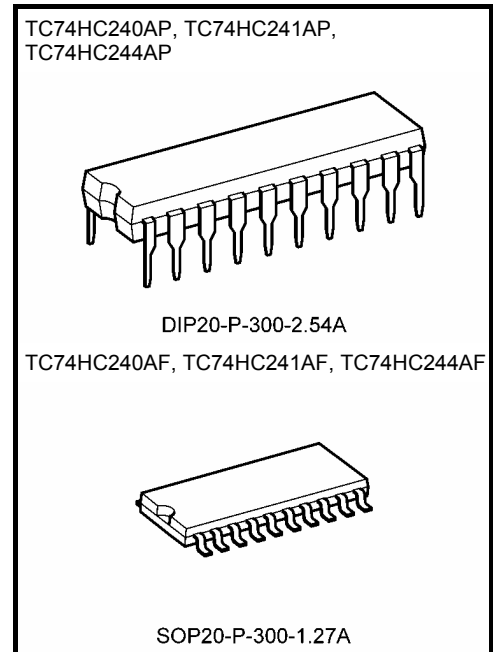
   The 74HC240A is an inverting 3-state buffer having two active-low output enables. The TC74HC241A and TC74HC244A are non-inverting 3-state buffers that differ only in that the 241A has one active-high and one active-low output enable, and the 244A has two active-low output enables.

   These devices are designed to be used with 3-state memory address drivers, etc.

   All inputs are equipped with protection circuits against static discharge or transient excess voltage.

TC74HC240AP, TC74HC241AP, TC74HC244AP

DIP20-P-300-2.54A

TC74HC240AF, TC74HC241AF, TC74HC244AF

SOP20-P-300-1.27A

Weight
DIP20-P-300-2.54A   : 1.30 g (typ.)
SOP20-P-300-1.27A   : 0.22 g (typ.)

Features

- High speed: t_{pd} = 10 ns (typ.) at V_{CC} = 5 V

- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C

- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)

- Output drive capability: 15 LSTTL loads

- Symmetrical output impedance: $|I_{OH}|$ = I_{OL} = 6 mA (min)

- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$

- Wide operating voltage range: V_{CC} (opr) = 2~6 V

- Pin and function compatible with 74LS240/241/244

Pin Assignment
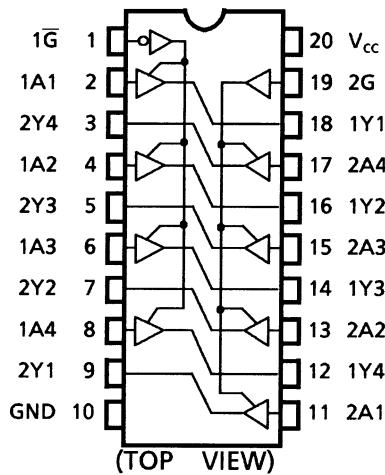
TC74HC240A

(TOP VIEW)

TC74HC241A

(TOP VIEW)

TC74HC244A

(TOP VIEW)
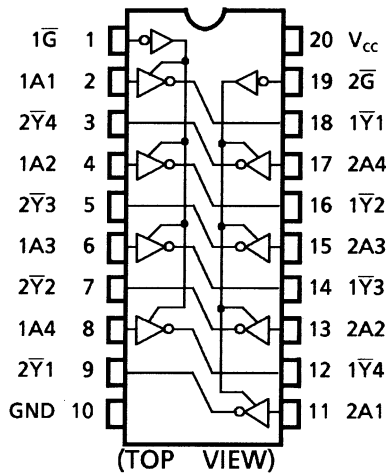
IEC Logic Symbol

TC74HC240A
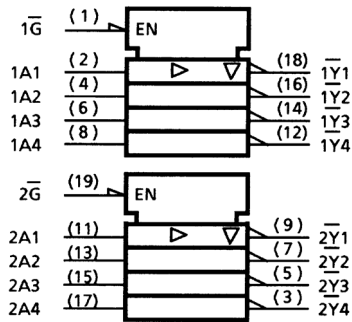
TC74HC241A
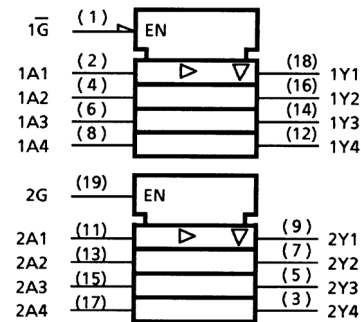
TC74HC244A
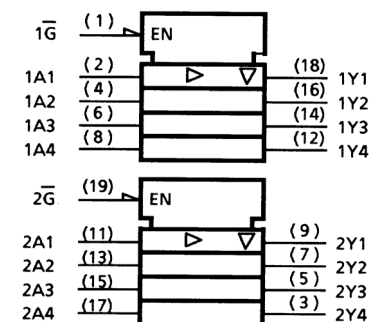
Truth Table

Inputs			Outputs	
$\overline{G}$	G^{Δ}	A_n	Y_n	$\overline{Y}_n$ $^{\Delta\Delta}$
L	H	L	L	H
L	H	H	H	L
H	L	X	Z	Z

Δ: For TC74HC241A only

$\Delta\Delta$: For TC74HC240A only

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5~7	V
DC input voltage	V_{IN}	−0.5~V_{CC} + 0.5	V
DC output voltage	V_{OUT}	−0.5~V_{CC} + 0.5	V
Input diode current	I_{IK}	±20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±35	mA
DC V_{CC}/ground current	I_{CC}	±75	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	−65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2~6	V
Input voltage	V_{IN}	0~V_{CC}	V
Output voltage	V_{OUT}	0~V_{CC}	V
Operating temperature	T_{opr}	−40~85	°C
Input rise and fall time	t_r, t_f	0~1000 (V_{CC} = 2.0 V) 0~500 (V_{CC} = 4.5 V) 0~400 (V_{CC} = 6.0 V)	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C			Ta = −40~85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				4.5	3.15	—	—	3.15	—	
				6.0	4.20	—	—	4.20	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				4.5	—	—	1.35	—	1.35	
				6.0	—	—	1.80	—	1.80	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	$I_{OH} = -20$ μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
				6.0	5.9	6.0	—	5.9	—	
			$I_{OH} = -6$ mA	4.5	4.18	4.31	—	4.13	—	
			$I_{OH} = -7.8$ mA	6.0	5.68	5.80	—	5.63	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	$I_{OL} = 20$ μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
				6.0	—	0.0	0.1	—	0.1	
			$I_{OL} = 6$ mA	4.5	—	0.17	0.26	—	0.33	
			$I_{OL} = 7.8$ mA	6.0	—	0.18	0.26	—	0.33	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		6.0	—	—	±0.5	—	±5.0	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	—	—	4.0	—	40.0	μA

AC Characteristics (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40~85°C		Unit
			CL (pF)	V_{CC} (V)	Min	Typ.	Max	Min	Max	
Output transition time	t_{TLH} t_{THL}	—	50	2.0	—	25	60	—	75	ns
				4.5	—	7	12	—	15	
				6.0	—	6	10	—	13	
Propagation delay time	t_{pLH} t_{pHL}	—	50	2.0	—	36	90	—	115	ns
				4.5	—	12	18	—	23	
				6.0	—	10	15	—	20	
			150	2.0	—	51	130	—	165	
				4.5	—	17	26	—	33	
				6.0	—	14	22	—	28	
Output enable time	t_{pZL} t_{pZH}	$R_L = 1$ kΩ	50	2.0	—	48	125	—	155	ns
				4.5	—	16	25	—	31	
				6.0	—	14	21	—	26	
			150	2.0	—	63	165	—	205	
				4.5	—	21	33	—	41	
				6.0	—	18	28	—	35	
Output disable time	t_{pLZ} t_{pHZ}	$R_L = 1$ kΩ	50	2.0	—	32	125	—	155	ns
				4.5	—	15	25	—	31	
				6.0	—	14	21	—	26	
Input capacitance	C_{IN}	—			—	5	10	—	10	pF
Output capacitance	C_{OUT}	—			—	10	—	—	—	pF
Power dissipation capacitance	C_{PD}	TC74HC240A			—	31	—	—	—	pF
	(Note)	TC74HC241A/244A			—	33	—	—	—	

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC} \text{ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

Package Dimensions

DIP20-P-300-2.54A   Unit : mm
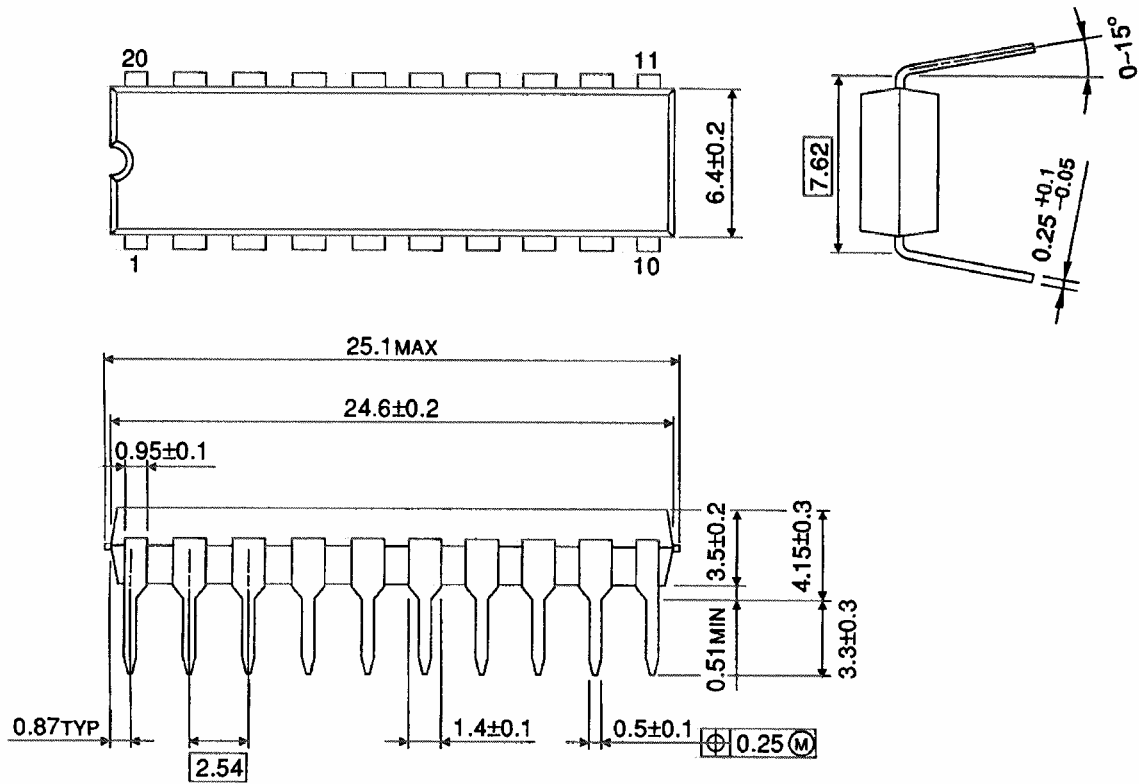
Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A   Unit: mm

20   11

5.3 ± 0.2
7.8 ± 0.3

1   10

0.685TYP   1.27   0.43 $^{+0.07}_{-0.04}$ ⊕ 0.25 Ⓜ

13.3MAX

12.8 ± 0.2

0.15 $^{+0.075}_{-0.035}$ 0～10°   0.25

1.9MAX

▱ 0.1

0.1 $^{+0.1}_{-0.05}$ 1.5 ± 0.2   0.8 ± 0.2

Weight: 0.22 g (typ.)

RESTRICTIONS ON PRODUCT USE

2007-10-01